NSN 5961-00-903-8023 Thyristor Semiconductor Device - Page 1 of 1



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nclosure Material:
Metal
Overall Length:
Between 0.250 inches and 0.450 inches
Overall Diameter:
0.875 inches
Mounting Facility Quantity:
2
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
3.5 gate trigger voltage, dc and 0.7 on-state voltage, dc
Current Rating Per Characteristic:
16.00 amperes forward current, total rms nanoamperes and 40.00 milliamperes forward current, total rms preset
Maximum Operating Tempurature Per Measurement Point:
35.0 degrees celsius case
Terminal Type And Quantity:
1 case and 2 uninsulated wire lead w/terminal lug
Specification Data:
30131-release3983 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Filg:
A110a0